

FAST RECOVERY DIODES

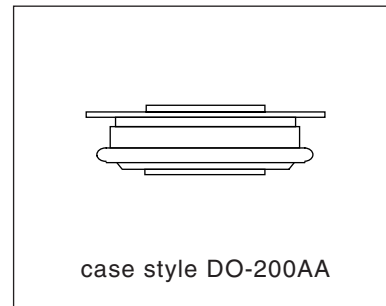
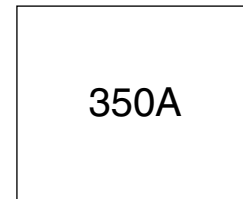
Hockey Puk Version

Features

- High power FAST recovery diode series
- 1.0 to 2.0 μ s recovery time
- High voltage ratings up to 2500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press-puk encapsulation
- Case style conform to JEDEC DO-200AA
- Maximum junction temperature 125°C

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications



Major Ratings and Characteristics

Parameters	SD303C..C	Units
$I_{F(AV)}$	350	A
	@ T_{hs}	55 °C
$I_{F(RMS)}$	550	A
	@ T_{hs}	25 °C
I_{FSM}	@ 50Hz	5770 A
	@ 60Hz	6040 A
I^2t	@ 50Hz	166 KA ² s
	@ 60Hz	152 KA ² s
V_{RRM} range	400 to 2500	V
t_{rr} range	1.0 to 2.0	μ s
	@ T_J	25 °C
T_J	- 40 to 125	°C

SD303C..C Series

Bulletin I2066 rev. C 04/00

International
IRF Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

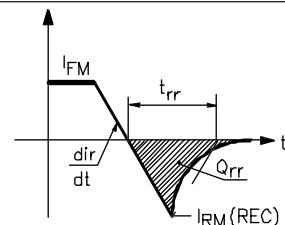
Type number	Voltage Code	V_{RRM} max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{RRM} max. $T_J = 125^\circ\text{C}$ mA
SD303C..S10C	04	400	500	35
	08	800	900	
	10	1000	1100	
SD303C..S15C	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
SD303C..S20C	20	2000	2100	
	25	2500	2600	

Forward Conduction

Parameter	SD303C..C	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Heatsink temperature	350(175)	A	180° conduction, half sine wave.
	55(75)	°C	Double side (single side) cooled
$I_{F(RMS)}$ Max. RMS current	550	A	@ 25°C heatsink temperature double side cooled
I_{FSM} Max. peak, one-cycle non-repetitive forward current	5770	A	t = 10ms No voltage reappplied
	6040		t = 8.3ms
	4850		t = 10ms 100% V_{RRM} reappplied
	5080		t = 8.3ms
I^2t Maximum I^2t for fusing	166	KA ² s	t = 10ms No voltage reappplied
	152		t = 8.3ms
	117		t = 10ms 100% V_{RRM} reappplied
	107		t = 8.3ms
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	1660	KA ² √s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level of threshold voltage	1.14	V	(16.7% x π x $I_{F(AV)}$) < I < π x $I_{F(AV)}$, $T_J = T_J$ max.
$V_{F(TO)2}$ High level of threshold voltage	1.63		(I > π x $I_{F(AV)}$), $T_J = T_J$ max.
r_{f1} Low level of forward slope resistance	1.14	mΩ	(16.7% x π x $I_{F(AV)}$) < I < π x $I_{F(AV)}$, $T_J = T_J$ max.
r_{f2} High level of forward slope resistance	0.77		(I > π x $I_{F(AV)}$), $T_J = T_J$ max.
V_{FM} Max. forward voltage	2.26	V	$I_{pk} = 1100\text{A}$, $T_J = 25^\circ\text{C}$, $t_p = 10\text{ms}$ sinusoidal wave

Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ typical t_{rr} @ 25% I_{RRM} (μs)	Test conditions			Max. values @ $T_J = 125^\circ\text{C}$		
		I_{pk} Square Pulse (A)	di/dt (A/μs)	V_r (V)	t_{rr} @ 25% I_{RRM} (μs)	Q_{rr} (μC)	I_{rr} (A)
S10	1.0	750	25	-30	2.4	52	33
S15	1.5				2.9	90	44
S20	2.0				3.2	107	46



Thermal and Mechanical Specifications

Parameter	SD303C..C	Units	Conditions
T _J Max. operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJ-hs} Max. thermal resistance, junction to heatsink	0.16 0.08	K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, ± 10%	4900 (500)		N (Kg)
wt Approximate weight	70	g	
Case style	DO-200AA		See Outline Table

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.010	0.011	0.008	0.008	K/W	T _J = T _J max.
120°	0.012	0.013	0.013	0.013		
90°	0.016	0.016	0.018	0.018		
60°	0.024	0.024	0.025	0.025		
30°	0.042	0.042	0.042	0.042		

Ordering Information Table

Device Code

SD	30	3	C	25	S20	C
①	②	③	④	⑤	⑥	⑦

- 1** - Diode
- 2** - Essential part number
- 3** - 3 = Fast recovery
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)
- 6** - t_{rr} code (see Recovery Characteristics table)
- 7** - C = Puk Case DO-200AA

SD303C..C Series

Bulletin I2066 rev. C 04/00

International
IOR Rectifier

Outline Table

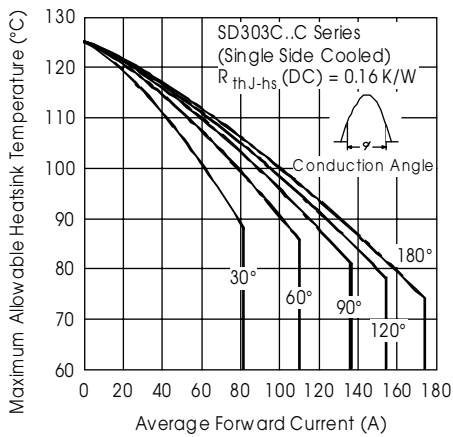
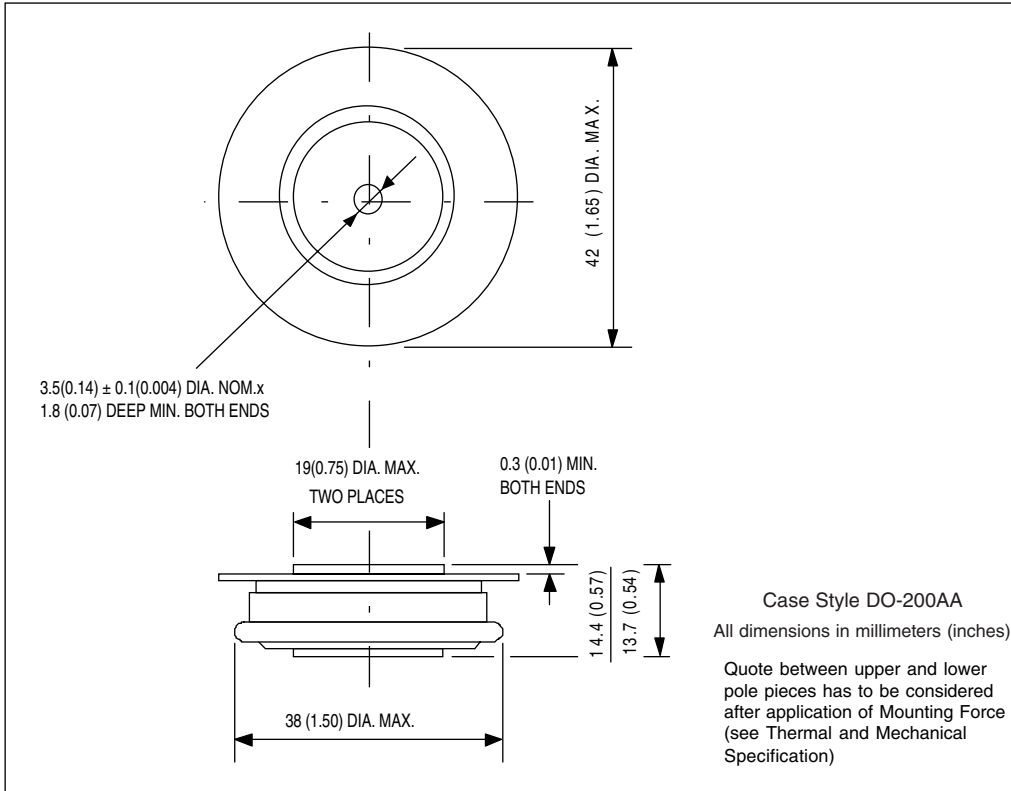


Fig. 1 - Current Ratings Characteristics

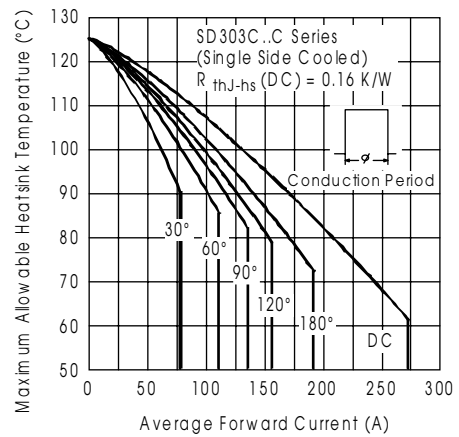


Fig. 2 - Current Ratings Characteristics

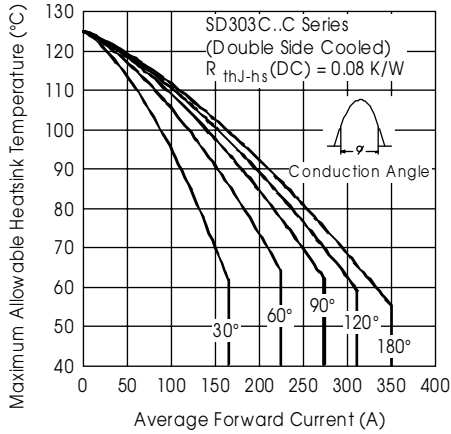


Fig. 3 - Current Ratings Characteristics

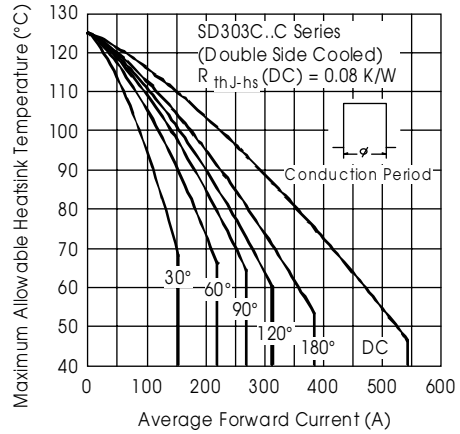


Fig. 4 - Current Ratings Characteristics

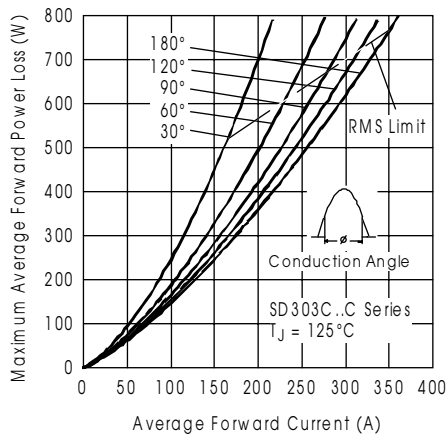


Fig. 5 - Forward Power Loss Characteristics

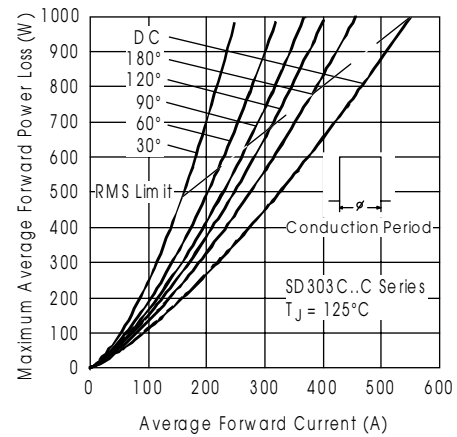


Fig. 6 - Forward Power Loss Characteristics

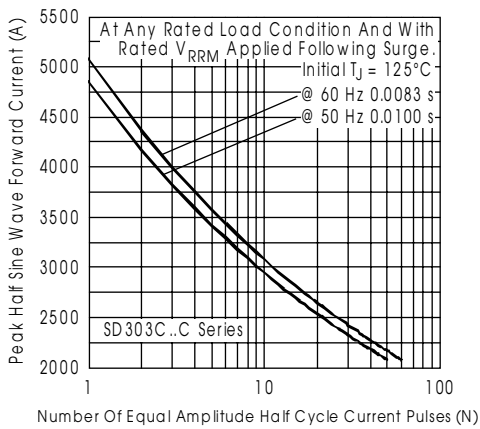


Fig. 7 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

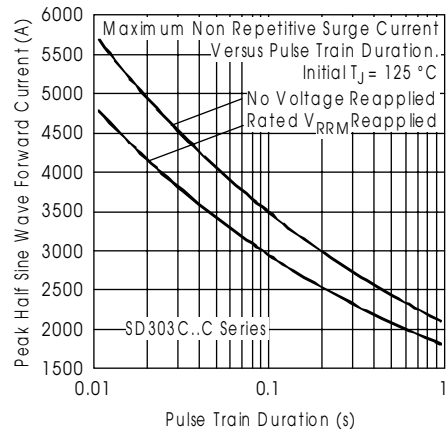


Fig. 8 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

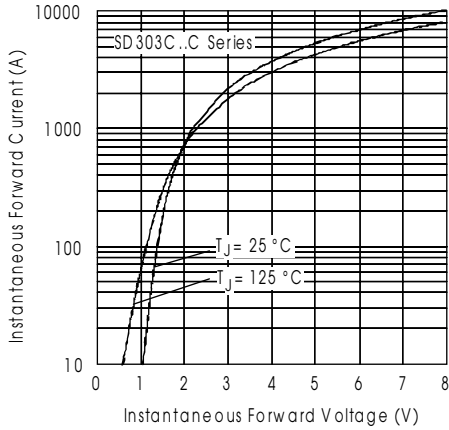


Fig. 9 - Forward Voltage Drop Characteristics

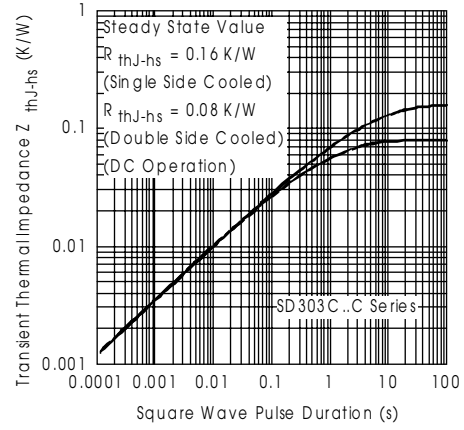


Fig. 10 - Thermal Impedance Z_{thj-hs} Characteristic

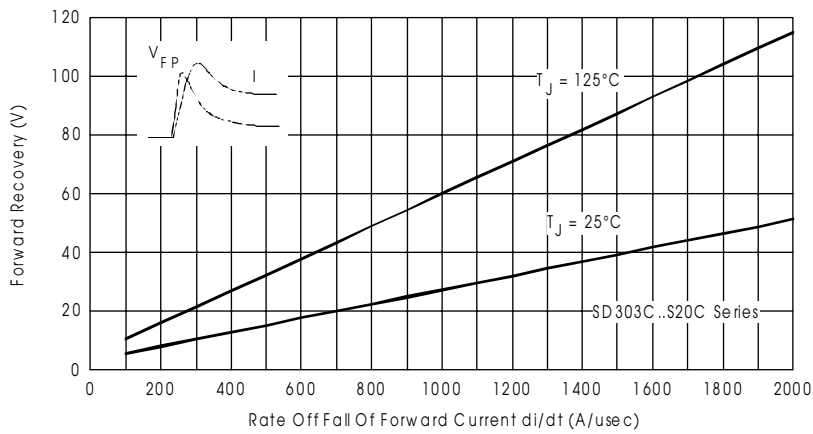


Fig. 11 - Typical Forward Recovery Characteristics

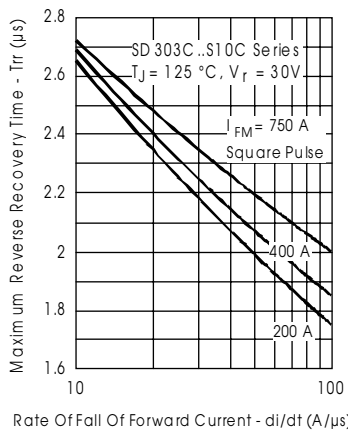


Fig. 12 - Recovery Time Characteristics

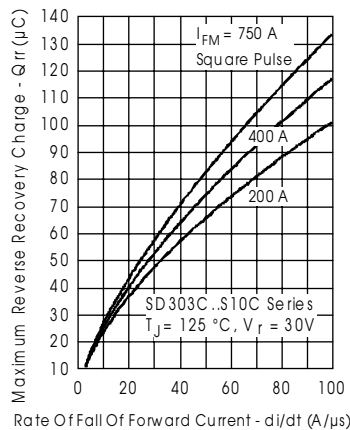


Fig. 13 - Recovery Charge Characteristics

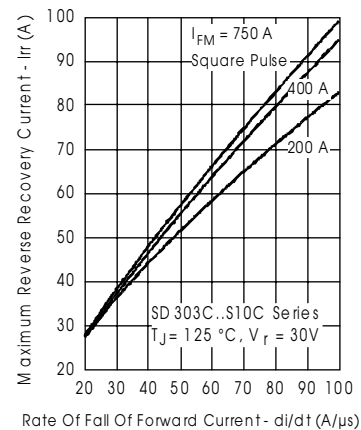


Fig. 14 - Recovery Current Characteristics

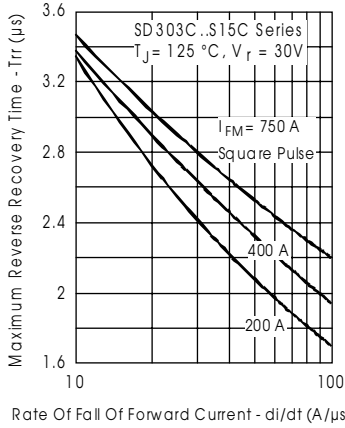


Fig. 15 - Recovery Time Characteristics

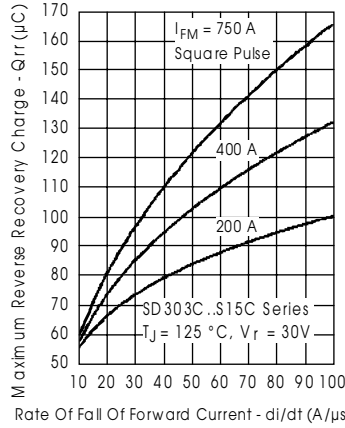


Fig. 16 - Recovery Charge Characteristics

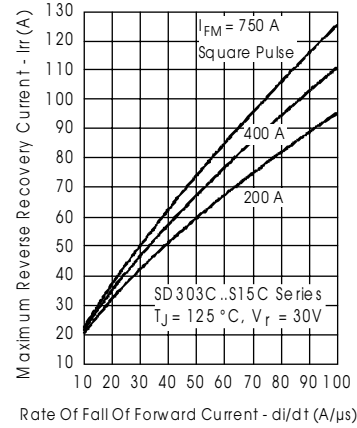


Fig. 17 - Recovery Current Characteristics

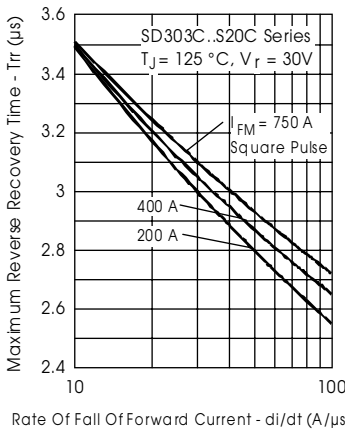


Fig. 18 - Recovery Time Characteristics

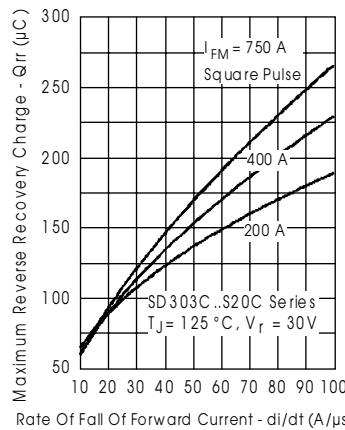


Fig. 19 - Recovery Charge Characteristics

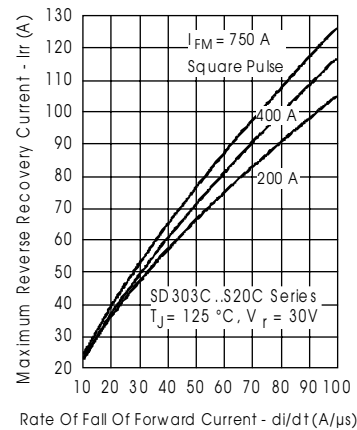


Fig. 20 - Recovery Current Characteristics

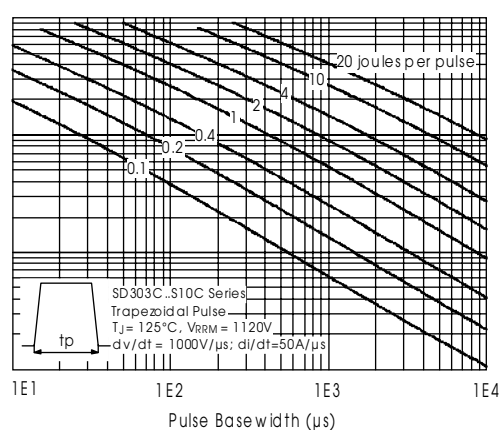
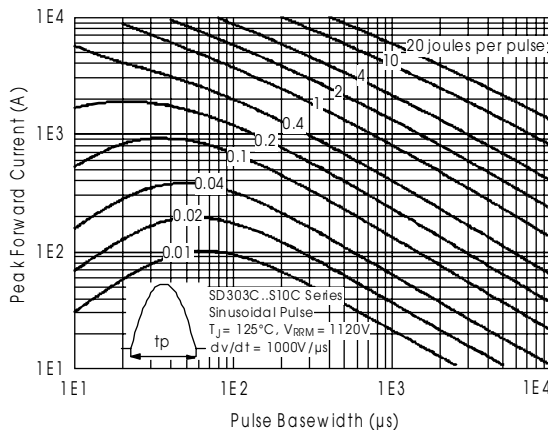


Fig. 21 - Maximum Total Energy Loss Per Pulse Characteristics

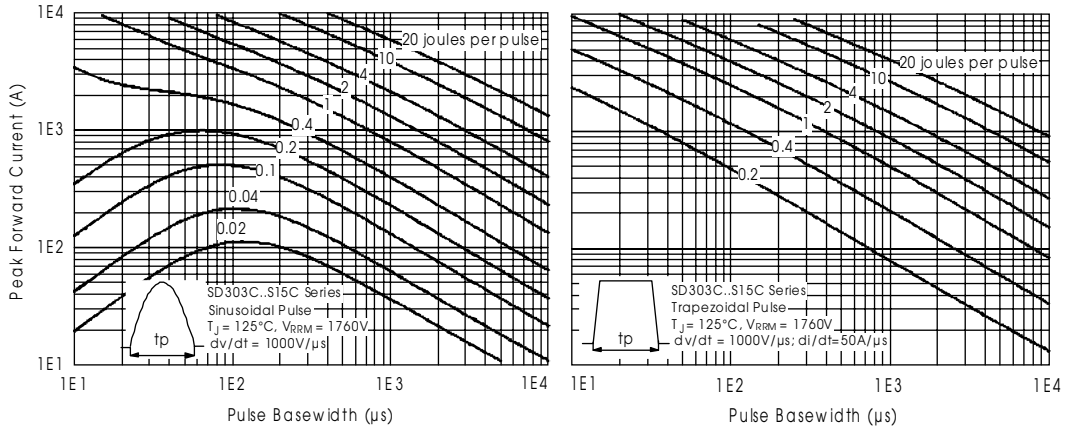


Fig. 22 - Maximum Total Energy Loss Per Pulse Characteristics

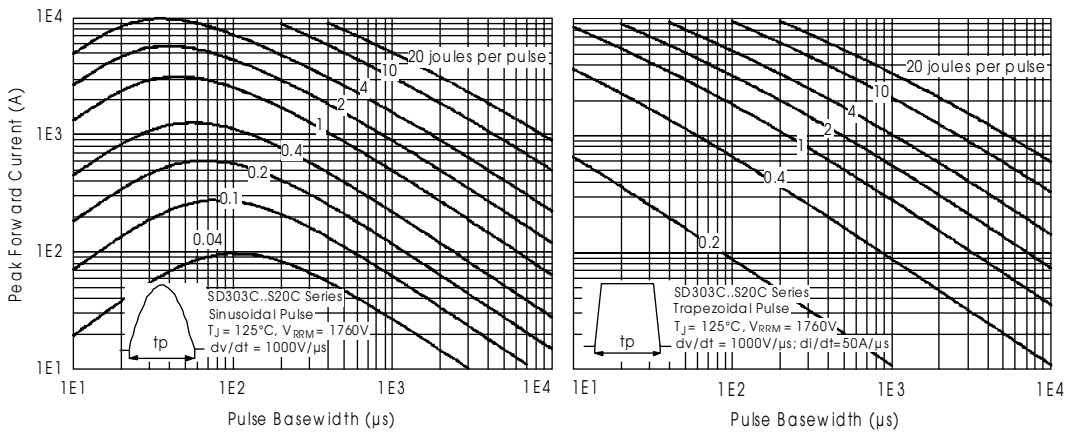


Fig. 23 - Maximum Total Energy Loss Per Pulse Characteristics